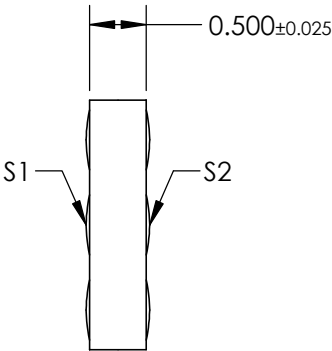
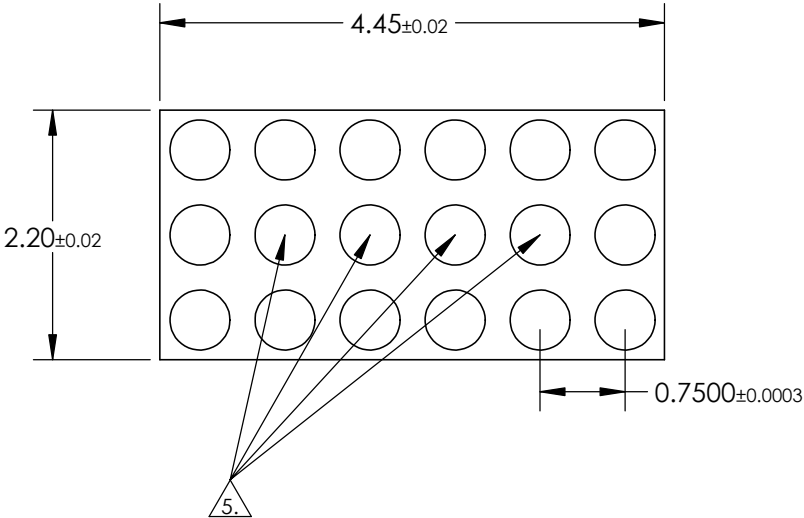
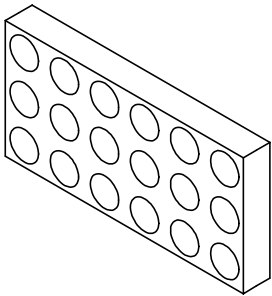


NOTES:

- 1. SUBSTRATE:  
Silicon
- 2. COATING (APPLY ACROSS COATING APERTURE):  
S1 & S2: R(AVG) ≤0.5% @ 1250 - 1620
- 3. WORKING DISTANCE (mm):  
0.304
- 4. MODE FIELD DIAMETER (mm):  
Source: 0.003  
Target: 0.25

5. ACTIVE LENSES CENTERED ON SUBSTRATE

6. ROHS: COMPLIANT



SPECIFICATIONS SUBJECT TO CHANGE WITHOUT NOTICE  
DIMENSIONS ARE FOR REFERENCE ONLY

**FOR INFORMATION ONLY:  
DO NOT MANUFACTURE  
PARTS TO THIS DRAWING**

**Edmund Optics®**

THIRD ANGLE PROJECTION		TITLE	4.45 x 2.20mm, 1.119 ROC, 750µm Pitch, Silicon, 1 x 4 Linear Microlens Array	
ALL DIMS IN	mm	DWG NO	21182	SHEET 1 OF 1